HEF4002B

Dual 4-input NOR gate

Rev. 4 — 17 October 2016

Product data sheet

1. General description

The HEF4002B is a dual 4-input NOR gate. The outputs are fully buffered for highest noise immunity and pattern insensitivity to output impedance variations.

It operates over a recommended V_{DD} power supply range of 3 V to 15 V referenced to V_{SS} (usually ground). Unused inputs must be connected to V_{DD} , V_{SS} , or another input.

2. Features and benefits

- Fully static operation
- 5 V, 10 V, and 15 V parametric ratings
- Standardized symmetrical output characteristics
- Inputs and outputs are protected against electrostatic effects
- Specified from –40 °C to +85 °C
- Complies with JEDEC standard JESD 13-B

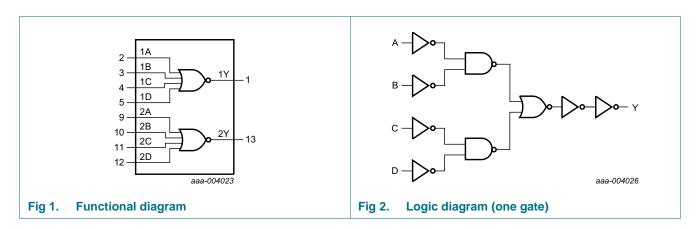
3. Ordering information

Table 1. Ordering information

All types operate from -40 °C to +85 °C.

Type number	Package				
	Name	Description	Version		
HEF4002BT	SO14	plastic small outline package; 14 leads; body width 3.9 mm	SOT108-1		

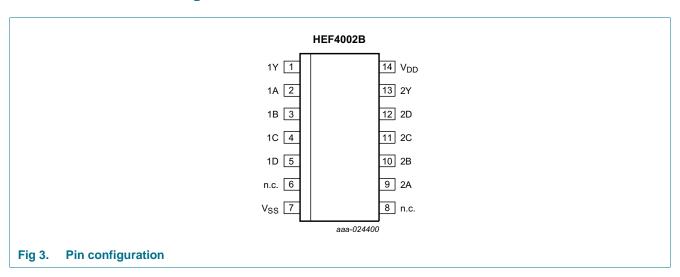
4. Functional diagram





5. Pinning information

5.1 Pinning



5.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
1A, 1B, 1C, 1D	2, 3, 4, 5	input
2A, 2B, 2C, 2D	9, 10, 11, 12	input
1Y, 2Y	1, 13	output
n.c.	6, 8	not connected
V _{SS}	7	ground (0 V)
V_{DD}	14	supply voltage

6. Functional description

Table 3. Function table[1]

Input	Output			
nA	nB	nC	nD	nY
L	L	L	L	Н
Н	Х	Х	X	L
X	Н	Х	X	L
X	X	Н	X	L
Х	X	X	Н	L

^[1] H = HIGH voltage level; L = LOW voltage level; X = don't care.

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to $V_{SS} = 0 \text{ V}$ (ground).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DD}	supply voltage		-0.5	+18	V
I _{IK}	input clamping current	$V_{I} < -0.5 \text{ V or } V_{I} > V_{DD} + 0.5 \text{ V}$	-	±10	mA
VI	input voltage		-0.5	V _{DD} + 0.5	V
I _{OK}	output clamping current	$V_{O} < -0.5 \text{ V or } V_{O} > V_{DD} + 0.5 \text{ V}$	-	±10	mA
I _{I/O}	input/output current		-	±10	mA
I _{DD}	supply current		-	50	mA
T _{stg}	storage temperature		- 65	+150	°C
T _{amb}	ambient temperature		-40	+85	°C
P _{tot}	total power dissipation	$T_{amb} = -40 ^{\circ}\text{C} \text{ to } +85 ^{\circ}\text{C}$			
		SO14 [1]	-	500	mW
Р	power dissipation	per output	-	100	mW

^[1] For SO14 packages: above T_{amb} = 70 °C, P_{tot} derates linearly with 8 mW/K.

8. Recommended operating conditions

Table 5. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DD}	supply voltage		3	15	V
VI	input voltage		0	V_{DD}	V
T _{amb}	ambient temperature	in free air	-40	+85	°C
Δt/ΔV	input transition rise and fall rate	V _{DD} = 5 V	-	3.75	μs/V
		V _{DD} = 10 V	-	0.5	μs/V
		V _{DD} = 15 V	-	0.08	μs/V

9. Static characteristics

Table 6. Static characteristics

 $V_{SS} = 0$ V; $V_I = V_{SS}$ or V_{DD} ; unless otherwise specified.

Symbol	Parameter	Conditions	V_{DD}	T _{amb} = -40 °C		T _{amb} = +25 °C		T _{amb} = +85 °C		Unit
				Min	Max	Min	Max	Min	Max	
V_{IH}	HIGH-level input voltage	$ I_{O} < 1 \mu A$	5 V	3.5	-	3.5	-	3.5	-	V
			10 V	7.0	-	7.0	-	7.0	-	V
			15 V	11.0	-	11.0	-	11.0	-	V
V_{IL}	LOW-level	$ I_{O} < 1 \mu A$	5 V	-	1.5	-	1.5	-	1.5	V
	input voltage		10 V	-	3.0	-	3.0	-	3.0	V
			15 V	-	4.0	-	4.0	-	4.0	V
V _{OH}	HIGH-level output voltage	$ I_{O} < 1 \mu A$	5 V	4.95	-	4.95	-	4.95	-	V
			10 V	9.95	-	9.95	-	9.95	-	V
			15 V	14.95	-	14.95	-	14.95	-	V
V_{OL}	LOW-level output voltage	$ I_{O} < 1 \mu A$	5 V	-	0.05	-	0.05	-	0.05	V
			10 V	-	0.05	-	0.05	-	0.05	V
			15 V	-	0.05	-	0.05	-	0.05	V
I _{OH}	HIGH-level output current	$V_0 = 2.5 \text{ V}$	5 V	-	-1.7	-	-1.4	-	-1.1	mA
		V _O = 4.6 V	5 V	-	-0.52	-	-0.44	-	-0.36	mA
		$V_0 = 9.5 \text{ V}$	10 V	-	-1.3	-	-1.1	-	-0.9	mA
		V _O = 13.5 V	15 V	-	-3.6	-	-3.0	-	-2.4	mA
I _{OL}	LOW-level output current	$V_0 = 0.4 \ V$	5 V	0.52	-	0.44	-	0.36	-	mA
		$V_0 = 0.5 \ V$	10 V	1.3	-	1.1	-	0.9	-	mA
		V _O = 1.5 V	15 V	3.6	-	3.0	-	2.4	-	mA
I _I	input leakage current		15 V	-	±0.3	-	±0.3	-	±1.0	μΑ
I _{DD}	supply current	all valid input	5 V	-	1.0	-	1.0	-	7.5	μΑ
		combinations;	10 V	-	2.0	-	2.0	-	15.0	μΑ
		$I_O = 0 A$	15 V	-	4.0	-	4.0	-	30.0	μΑ
Cı	input capacitance			-	-	-	7.5	-	-	pF

10. Dynamic characteristics

Table 7. Dynamic characteristics

 T_{amb} = 25 °C; C_L = 50 pF; t_r = $t_f \le$ 20 ns; waveforms see <u>Figure 4</u>; test circuit see <u>Figure 5</u>; unless otherwise specified. [1]

Symbol	Parameter	Conditions	V_{DD}	Extrapolation formula	Min	Тур	Max	Unit
t _{pd}	propagation delay	nA, nB, nC,	5 V [2]	33 + 0.55 × C _L	-	60	120	ns
		nD to nY	10 V	14 + 0.23 × C _L	-	25	50	ns
			15 V	12 + 0.16 × C _L	-	20	40	ns
t _{THL}	HIGH to LOW output	nY	5 V	10 + 1.0 × C _L	-	60	120	ns
	transition time		10 V	9 + 0.42 × C _L	-	30	60	ns
			15 V	6 + 0.28 × C _L	-	20	40	ns
t _{TLH}	LOW to HIGH output	nY	5 V	10 + 1.0 × C _L	-	60	120	ns
transition time		10 V	9 + 0.42 × C _L	-	30	60	ns	
			15 V	6 + 0.28 × C _L	-	20	40	ns

^[1] The typical value of the propagation delay and output transition time can be calculated with the extrapolation formula (C_L in pF).

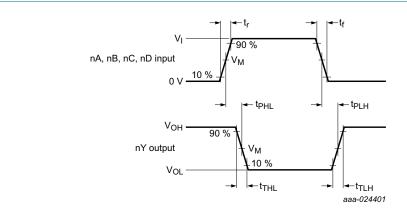
Table 8. Dynamic power dissipation

 $V_{SS} = 0 \text{ V; } t_r = t_f \le 20 \text{ ns; } T_{amb} = 25 \text{ °C.}$

Symbol	Parameter	V_{DD}	Typical formula	where:
P_D	dynamic power dissipation	5 V	$P_D = 1050 \times f_i + \Sigma(f_o \times C_L) \times V_{DD}^2 (\mu W)$	f_i = input frequency in MHz;
		10 V	$P_D = 4300 \times f_i + \Sigma (f_o \times C_L) \times V_{DD}^2 (\mu W)$	fo = output frequency in MHz;
		15 V	$P_{D} = 11700 \times f_{i} + \Sigma (f_{o} \times C_{L}) \times V_{DD}^{2} (\mu W)$	C_L = output load capacitance in pF;
				$\Sigma(f_0 \times C_L)$ = sum of the outputs;
				V_{DD} = supply voltage in V.

^[2] t_{pd} is the same as t_{PHL} and t_{PLH} .

11. Waveforms



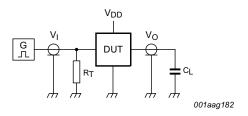
Measurement points are given in Table 9.

Logic levels: V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Fig 4. Input to output propagation delay and output transition times

Table 9. Measurement points

Supply voltage	Input	Output
V_{DD}	V _M	V _M
5 V to 15 V	0.5V _{DD}	0.5V _{DD}



Test data is given in Table 10.

Definitions for test circuit:

DUT = Device Under Test.

 C_L = load capacitance including jig and probe capacitance.

 R_T = termination resistance should be equal to the output impedance Z_0 of the pulse generator.

Fig 5. Test circuit for measuring switching times

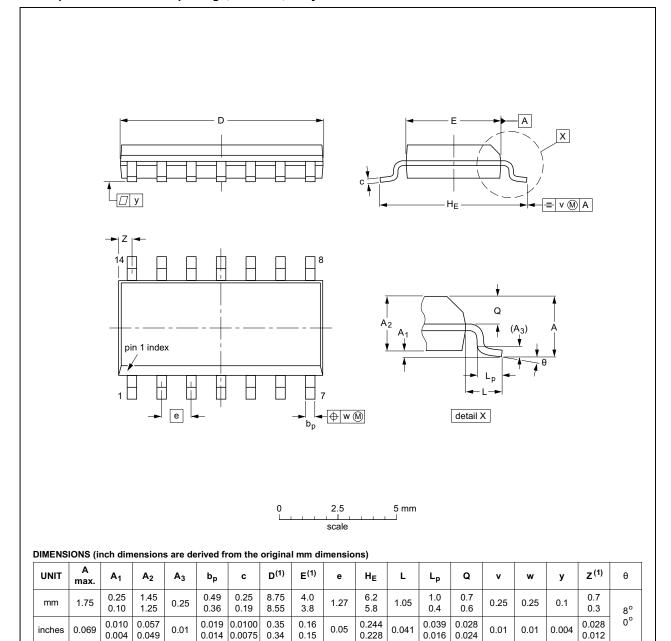
Table 10. Test data

Supply voltage	Input	Load	
V _{DD}	VI	t _r , t _f	CL
5 V to 15 V	V _{SS} or V _{DD}	≤ 20 ns	50 pF

12. Package outline

SO14: plastic small outline package; 14 leads; body width 3.9 mm

SOT108-1



Note

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE	
SOT108-1	076E06	MS-012				99-12-27 03-02-19	

Fig 6. Package outline SOT108-1 (SO14)

HEF4002B

13. Abbreviations

Table 11. Abbreviations

Acronym	Description
DUT	Device Under Test

14. Revision history

Table 12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
HEF4002B v.4	20161017	Product data sheet	-	HEF4002B_CNV v.3
Modifications:	 The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors. Legal texts have been adapted to the new company name where appropriate. 			
HEF4002B_CNV v.3	19950101	Product specification	-	HEF4002B_CNV v.2
HEF4002B_CNV v.2	19950101	Product specification	-	-

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Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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